[2345/119]

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

cant(s)

Hartwig RICHTER et al.

Serial No.

09/529,700

Filed

April 18, 2000

Title

SEMICONDUCTOR LASER CHIP

Art Unit

2828

Examiner

James Davie

Mail Stop AF

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on

TRANSMITTAL OF AMENDMENT

SIR:

Transmitted herewith for filing in the above-identified patent application is an Amendment in response to an Office Action made Final dated June 2, 2003.

No fee is believed due at this time. However, the Commissioner is authorized, as appropriate and/or necessary, to charge any additional fees (including any Rule 136(a) extension fees) or credit any overpayment to Deposit Account No. 11-0600. A duplicate copy of this transmittal letter is enclosed for that purpose.

Respectfully submitted,

By:

Dated: 24, 203

Richard L. Mayer

(Reg. No. 22,490)

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[2345/119]

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Commissioner for Patents, P.O. Box 1450, Alexandria, VA 223

Date: June 24, 2003

Signature Judy Linda M. Shudy (Reg. no. 47,084)

AMENDMENT

Sir:

In response to the Office Action dated June 2, 2003, please reconsider the above-

identified application based on the following:

ENTERE 7/16/3.

IN THE CLAIMS:

Please amend claims 35, 38, 41 and 45 as follows:

35. (Amended) The semiconductor laser as recited in claim 34 wherein prior to the welding

38. (Amended) The semiconductor laser as recited in claim 37 wherein the wires for measuring the electrical resistance through the semiconductor laser chip include a pumping

each of the at least one temperature sensor is sealed into an electrically insulating glass.

current lead wire and an additional wire used as a sensor supply lead.

41. (Amended) The semiconductor laser as recited in claim 40 wherein a contact surface of a material of one of the wires is deposited on the semiconductor laser chip before the two wires are joined.

DZ

D3